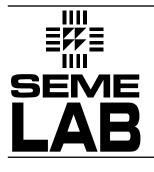
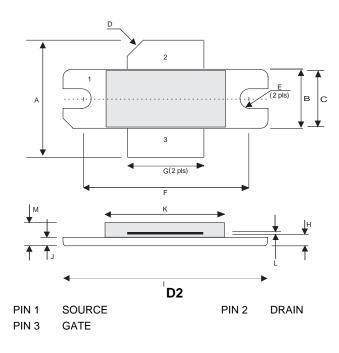
TetraFET

DMD1006 DMD1006-A



ROHS COMPLIANT METAL GATE RF SILICON FET

MECHANICAL DATA



DIM	Millimetres	Tol.	Inches	Tol.
A	19.43	0.13	0.765	0.005
В	9.78	0.13	0.385	0.005
С	9.40	0.10	0.370	0.004
D	45°	5°	45°	5°
E	1.63R	0.13	0.064R	0.005
F	27.94	0.13	1.100	0.005
G	12.70	0.13	0.500	0.005
Н	1.57	0.13	0.062	0.005
I	34.04	0.13	1.340	0.005
J	1.01	0.13	0.040	0.005
K	19.94	0.25	0.785	0.009
L	0.10	0.25	0.004	0.002
М	4.24	0.25	0.167	0.01

GOLD METALLISED MULTI-PURPOSE SILICON **DMOS RF FET** 150W – 28V – 175MHz SINGLE ENDED

FEATURES

- SUITABLE FOR BROAD BAND APPLICATIONS
- SIMPLE BIAS CIRCUITS
- ULTRA-LOW THERMAL RESISTANCE
- BeO FREE
- LOW C_{rss}
- HIGH GAIN 15 dB MINIMUM

APPLICATIONS

 HF/VHF/UHF COMMUNICATIONS from 1 MHz to 200 MHz

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

PD	Power Dissipation	438W (219W - A Version)
BV _{DSS}	Drain – Source Breakdown Voltage	70V
BV _{GSS}	Gate – Source Breakdown Voltage	±20V
I _{D(sat)}	Drain Current	30A
T _{stg}	Storage Temperature	–65 to 150°C
Tj	Maximum Operating Junction Temperature	200°C

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Test Conditions Min. Unit Parameter Тур. Max. Drain-Source BV_{DSS} $V_{GS} = 0$ $I_{D} = 100 \text{mA}$ 70 V Breakdown Voltage Zero Gate Voltage $V_{DS} = 28V$ $V_{GS} = 0$ 6 mΑ IDSS **Drain Current** $V_{GS} = 20V$ $V_{DS} = 0$ Gate Leakage Current 1 μΑ IGSS $V_{DS} = V_{GS}$ Gate Threshold Voltage* $I_D = 10 mA$ 1 7 V V_{GS(th)} $V_{DS} = 10V$ Forward Transconductance* $I_D = 6A$ S 4.8 9_{fs} **Common Source Power Gain** $P_{O} = 150W$ 15 dB G_{PS} **Drain Efficiency** $V_{DS} = 28V$ $I_{DQ} = 1.2A$ 50 % η VSWR Load Mismatch Tolerance f = 175MHz 20:1 ____ $V_{GS} = -5V f = 1MHz$ Input Capacitance $V_{DS} = 0V$ 360 pF Ciss C_{oss} f = 1MHz**Output Capacitance** V_{DS} = 28V $V_{GS} = 0$ 180 pF **Reverse Transfer Capacitance** V_{DS} = 28V $V_{GS} = 0$ f = 1MHz15 pF Crss

ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

* Pulse Test: Pulse Duration = $300 \ \mu s$, Duty Cycle $\leq 2\%$

THERMAL DATA

R _{THi-case}	Thermal Resistance Junction – Case	Max. 0.4°C / W
,		0.8 °C / W -A Version

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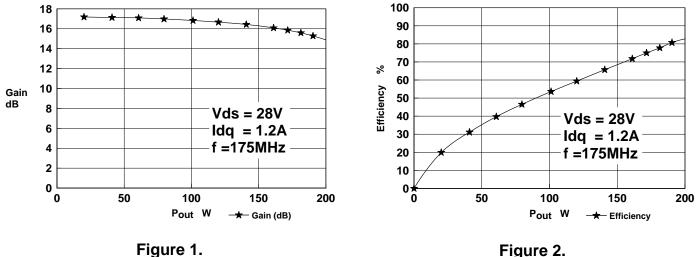
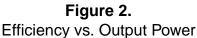


Figure 1. Gain vs.Output Power



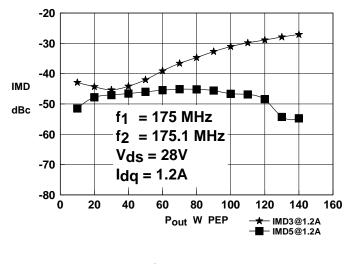


Figure 3. IMD vs Output Power

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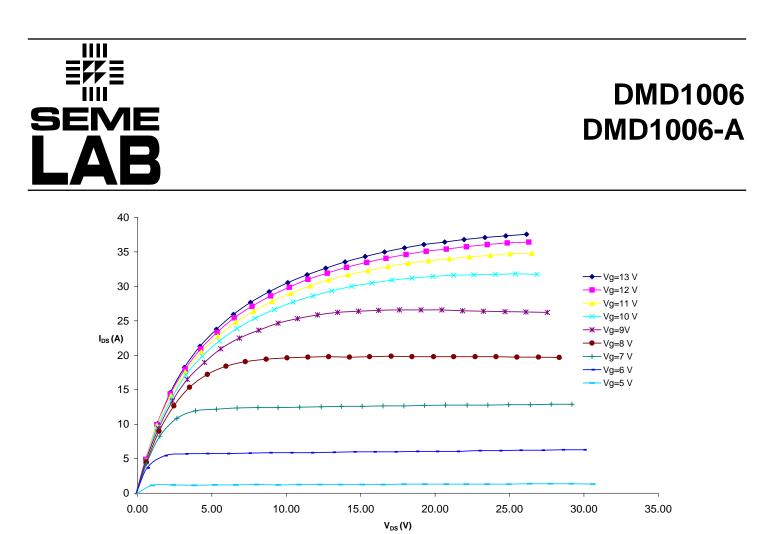
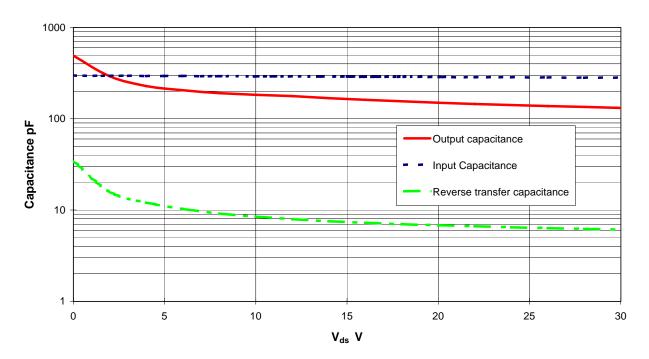


Figure 4 – Typical IV Characteristics.

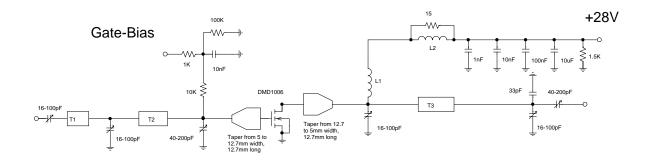




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175 MHz Test Fixture

Substrate 1.6mm PTFE/glass, Er = 2.5 All microstrip lines W = 5mm

- T1 7.5mm
- T2 16mm
- T3 20mm
- L1 9 turns 20swg encamelled copper wire, 6mm i.d.
- L2 11 turns 19swg enamelled copper wire on Fair-Rite FT82 ferrite core

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